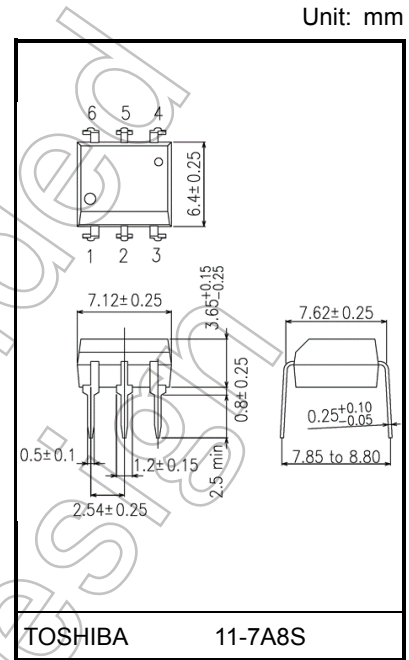


TLP331, TLP332

Programmable Controllers
AC/DC-Input Module
Telecommunication

The TOSHIBA TLP331 and TLP332 consist of an infrared emitting diode optically coupled to a photo-transistor in a six lead plastic DIP package. This photocoupler provides the unique feature of high current transfer ratio at both low output voltage and low input current. This makes it ideal for use in low power logic circuits, telecommunications equipment and portable electronics isolation applications. TLP332 has no-base internal connection for high-EMI environments.

- Collector-emitter voltage: 55 V (min)
- Isolation voltage: 5000 Vrms (min)
- UL-recognized: UL 1577, File No.E67349
- cUL-recognized: CSA Component Acceptance Service No.5A
File No.E67349
- Current transfer ratio



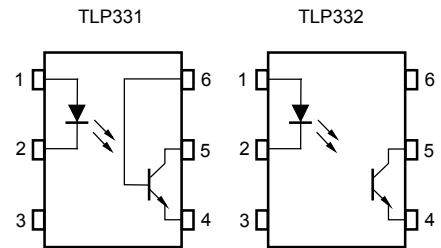
Unit: mm
Weight: 0.4 g (typ.)

Classification (Note 1)	Current Transfer Ratio (min)			Marking of Classification
	Ta = 25°C		Ta = -25 to 75°C	
	If = 1 mA VCE = 0.5V	If = 0.5 mA VCE = 1.5V	If = 1 mA VCE = 0.5V	
Rank BV	200%	100%	100%	BV
Standard	100%	50%	50%	BV, blank

Note 1: ex. Standard: TLP331
Rank BV: TLP331(BV)

Note: Application type name for certification test,
please use standard product type name, i.e.
TLP331(BV): TLP331

Pin Configurations (top view)



- 1: ANODE
2: CATHODE
3: NC
4: EMITTER
5: COLLECTOR
6: BASE

- 1: ANODE
2: CATHODE
3: NC
4: EMITTER
5: COLLECTOR
6: NC

Start of commercial production
1986-03

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
LED	Forward current	I_F	50	mA
	Forward current derating (Ta ≥ 39°C)	$\Delta I_F/^\circ\text{C}$	-0.7	mA/°C
	Peak forward current (100 μs pulse, 100 pps)	I_{FP}	1	A
	Reverse Voltage	V_R	5	V
	Diode power dissipation	P_D	50	mW
	Diode power dissipation derating (Ta > 39 °C)	$\Delta P_D/^\circ\text{C}$	-0.58	mW/°C
	Junction temperature	T_j	125	°C
Detector	Collector-emitter voltage	V_{CEO}	55	V
	Collector-base voltage (TLP331)	V_{CBO}	80	V
	Emitter-collector voltage	V_{ECO}	7	V
	Emitter-base voltage (TLP331)	V_{EBO}	7	V
	Collector current	I_C	50	mA
	Power dissipation	P_C	150	mW
	Power dissipation derating (Ta ≥ 25°C)	$\Delta P_C/^\circ\text{C}$	-1.5	mW/°C
	Junction temperature	T_j	125	°C
Storage temperature range		T_{stg}	-55 to 125	°C
Operating temperature range		T_{opr}	-55 to 100	°C
Lead soldering temperature (10 s)		T_{sol}	260	°C
Total package power dissipation		P_T	250	mW
Total package power dissipation derating (Ta ≥ 25°C)		$P_T/^\circ\text{C}$	-2.5	mW/°C
Isolation voltage (AC, 60 s, RH ≤ 60 %)		(Note 1) BV_S	5000	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

Note 1: Device considered a two terminal device: Pins 1, 2 and 3 shorted together and pins 4, 5 and 6 shorted together.

Recommended Operating Conditions

Characteristics	Symbol	Min	Typ.	Max	Unit
Supply voltage	V_{CC}	—	5	25	V
Forward current	I_F	—	1.6	25	mA
Collector current	I_C	—	1	10	mA
Operating temperature	T_{opr}	-25	—	75	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
LED	Forward voltage	V_F	$I_F = 10 \text{ mA}$	1.0	1.15	1.3	V
	Reverse current	I_R	$V_R = 5 \text{ V}$	—	—	10	μA
	Capacitance	C_T	$V = 0 \text{ V}, f = 1 \text{ MHz}$	—	30	—	pF
Detector	Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C = 0.5 \text{ mA}$	55	—	—	V
	Emitter-collector breakdown voltage	$V_{(BR)ECO}$	$I_E = 0.1 \text{ mA}$	7	—	—	V
	Collector-base breakdown voltage (TLP331)	$V_{(BR)CBO}$	$I_C = 0.1 \text{ mA}$	80	—	—	V
	Emitter-base breakdown voltage (TLP331)	$V_{(BR)EBO}$	$I_E = 0.1 \text{ mA}$	7	—	—	V
	Collector dark current	I_{CEO}	$V_{CE} = 24 \text{ V}$	—	10	100	nA
			$V_{CE} = 24 \text{ V}, T_a = 85^\circ\text{C}$	—	2	50	μA
	Collector dark current (TLP331)	I_{CER}	$V_{CE} = 24 \text{ V}, T_a = 85^\circ\text{C}$ $R_{BE} = 1 \text{ M}\Omega$	—	0.5	10	μA
	Collector dark current (TLP331)	I_{CBO}	$V_{CB} = 10 \text{ V}$	—	0.1	—	nA
	DC forward current gain (TLP331)	h_{FE}	$V_{CE} = 5 \text{ V}, I_C = 0.5 \text{ mA}$	—	1000	—	—
Capacitance (collector to emitter)	C_{CE}	$V = 0 \text{ V}, f = 1 \text{ MHz}$	—	12	—	pF	

Coupled Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Current transfer ratio	I_C/I_F	$I_F = 1 \text{ mA}, V_{CE} = 0.5 \text{ V}$ Rank BV	100	—	1200	%
			200	—	1200	
Low input CTR	$I_C/I_{F(\text{low})}$	$I_F = 0.5 \text{ mA}, V_{CE} = 1.5 \text{ V}$ Rank BV	50	—	—	%
			100	—	—	
Base photo-current (TLP331)	I_{PB}	$I_F = 1 \text{ mA}, V_{CB} = 5 \text{ V}$	—	10	—	μA
Collector-emitter saturation voltage	$V_{CE(\text{sat})}$	$I_C = 0.5 \text{ mA}, I_F = 1 \text{ mA}$ $I_C = 1 \text{ mA}, I_F = 1 \text{ mA}$ Rank BV	—	—	0.4	V
			—	0.2	—	
			—	—	0.4	

Coupled Electrical Characteristics (Ta = 25 to 75°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Current transfer ratio	I_C/I_F	$I_F = 1 \text{ mA}, V_{CE} = 0.5 \text{ V}$ Rank BV	50	—	—	%
			100	—	—	
Low input CTR	$I_C/I_{F(\text{low})}$	$I_F = 0.5 \text{ mA}, V_{CE} = 1.5 \text{ V}$ Rank BV	—	50	—	%
			—	100	—	

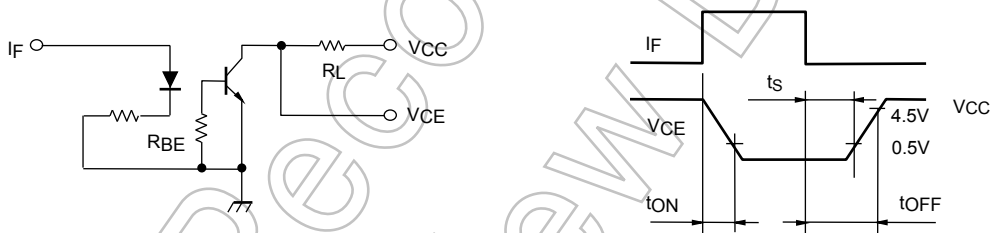
Isolation Characteristics (Ta = 25°C)

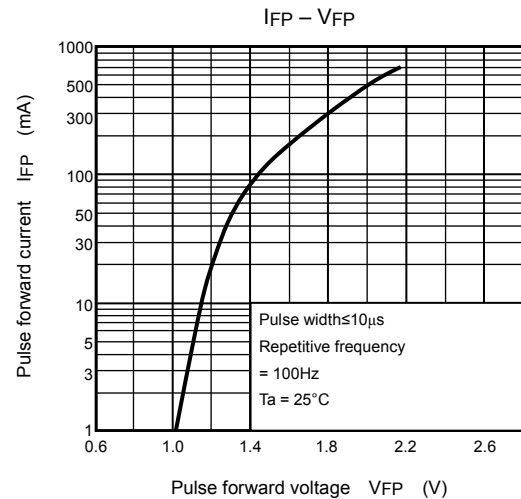
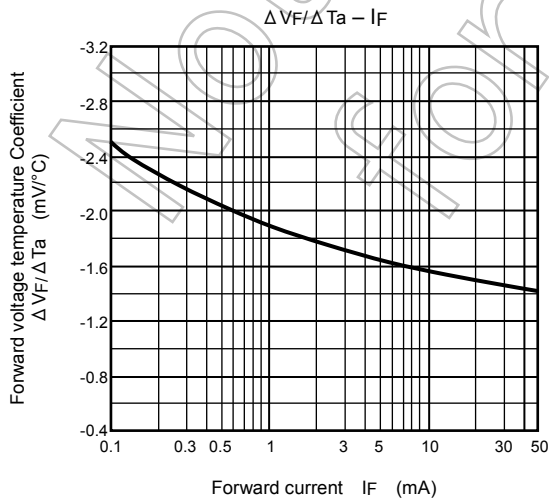
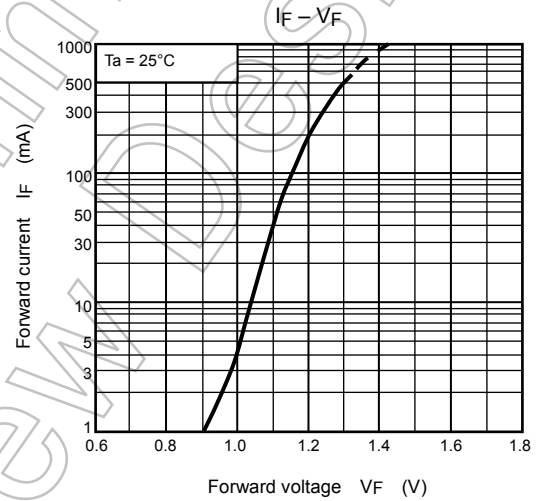
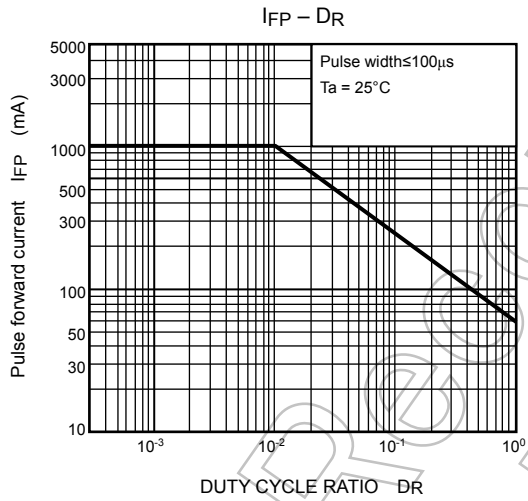
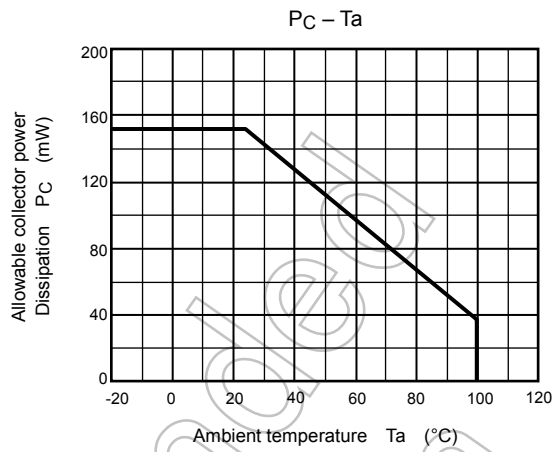
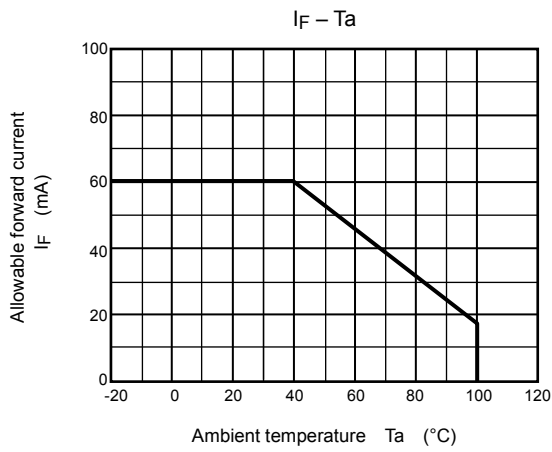
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Capacitance (input to output)	C _S	V _S = 0 V, f = 1 MHz	—	0.8	—	pF
Isolation resistance	R _S	V = 500 V, RH ≤ 60 %	5×10 ¹⁰	10 ¹⁴	—	Ω
Isolation voltage	BV _S	AC, 60 s	5000	—	—	V _{rms}

Switching Characteristics (Ta = 25°C)

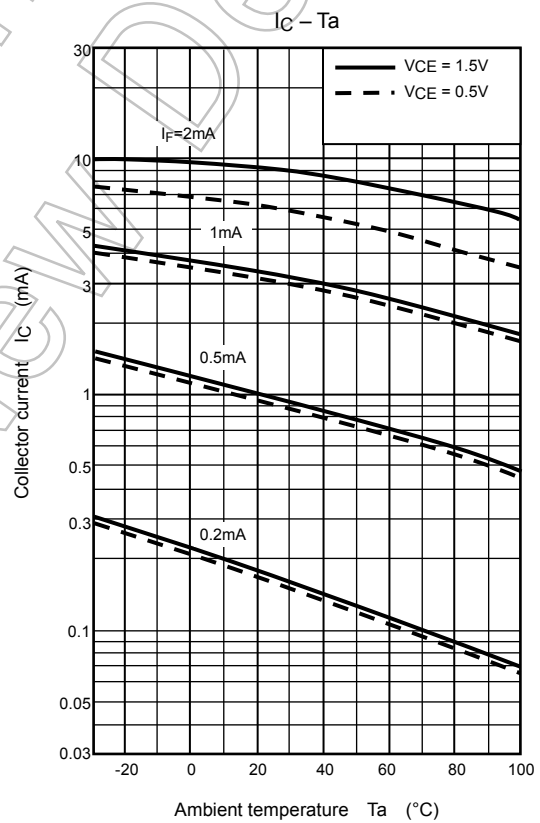
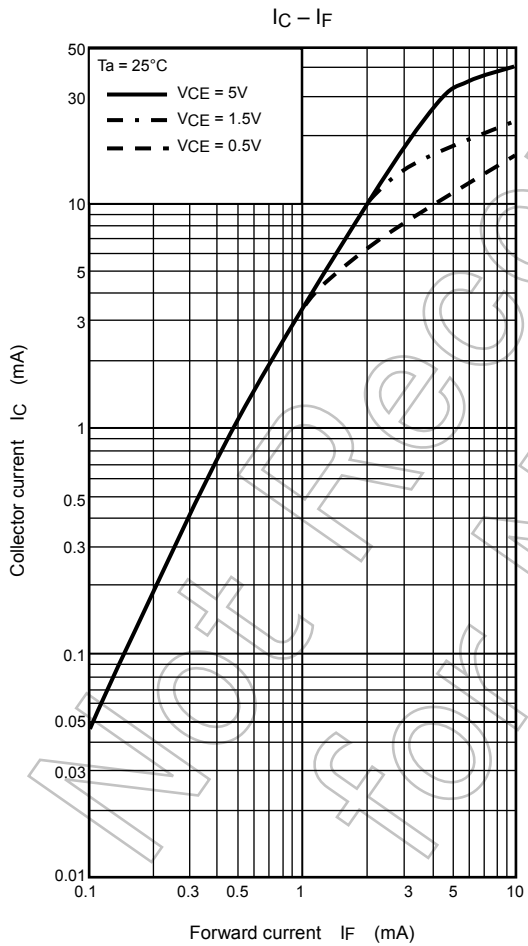
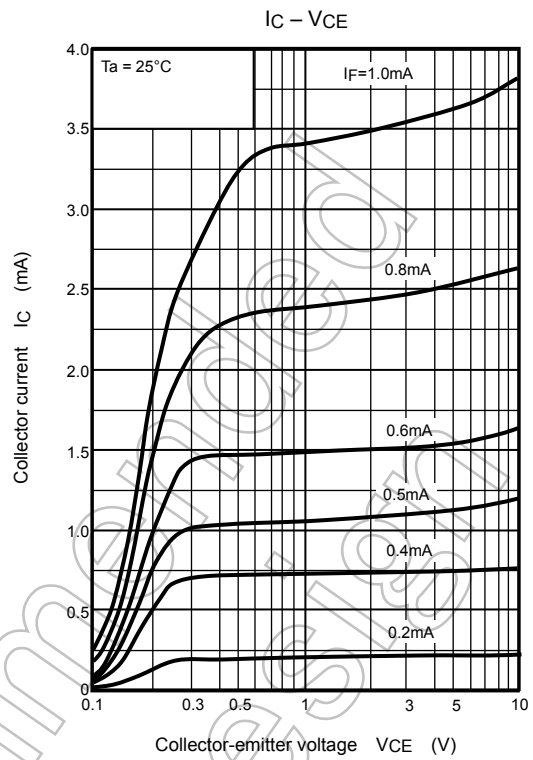
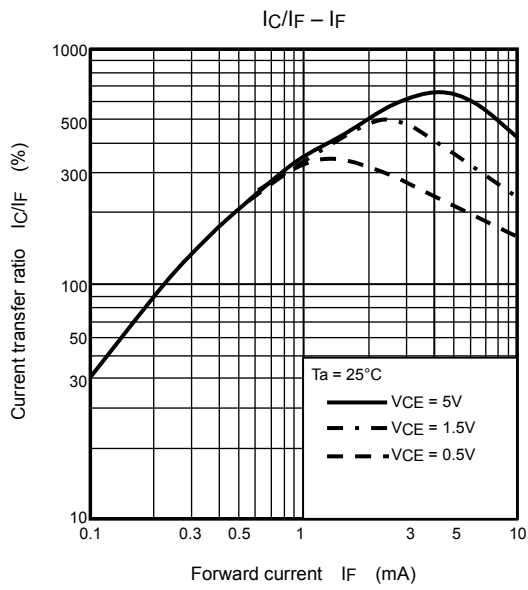
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Rise time	t _r	V _{CC} = 10 V, I _C = 2 mA R _L = 100 Ω	—	8	—	μs
Fall time	t _f		—	8	—	
Turn-on time	t _{on}		—	10	—	
Turn-off time	t _{off}		—	8	—	
Turn-on time	t _{ON}	R _L = 4.7 kΩ (Fig.1) R _{BE} = OPEN V _{CC} = 5 V, I _F = 1.6 mA	—	10	—	μs
Storage time	t _s		—	50	—	
Turn-off time	t _{OFF}		—	300	—	
Turn-on time	t _{ON}	R _L = 4.7 kΩ (Fig.1) R _{BE} = 470 kΩ (TLP331) V _{CC} = 5 V, I _F = 1.6 mA	—	12	—	μs
Storage time	t _s		—	30	—	
Turn-off time	t _{OFF}		—	100	—	

Fig. 1 Switching time test circuit

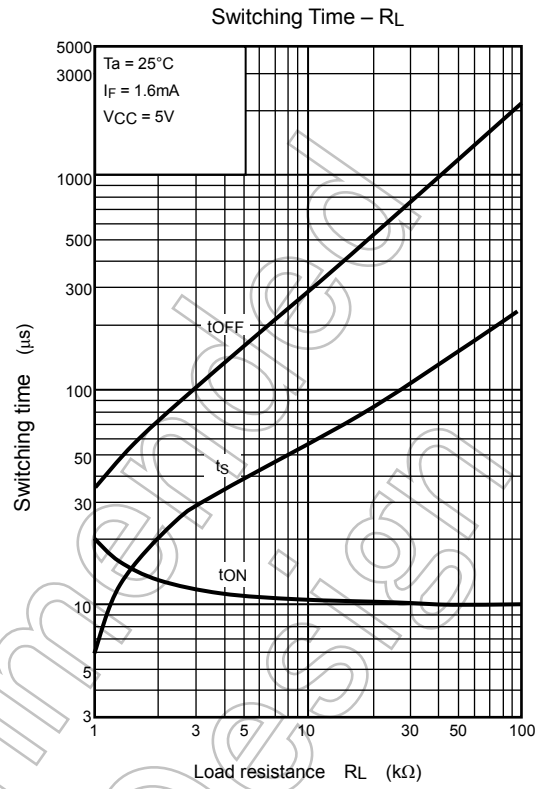
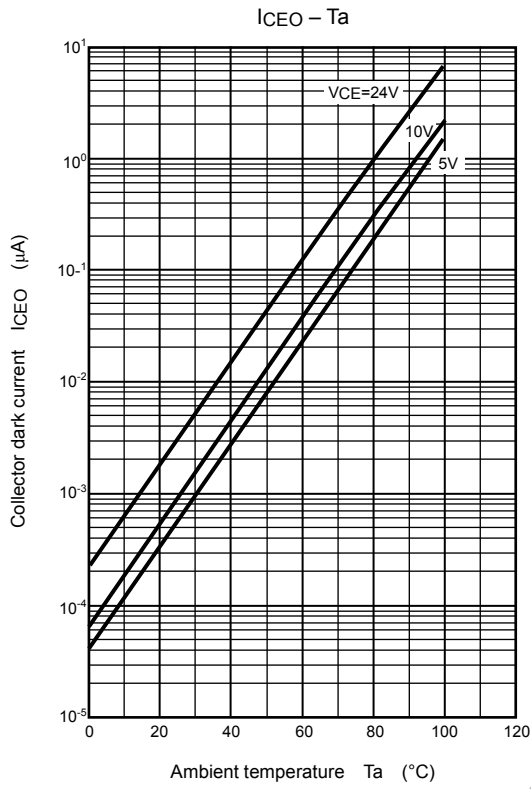




NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



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Not Recommended for New Design

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